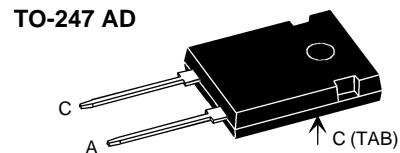


HiPerFRED™ Epitaxial Diode with soft recovery

I_{FAV} = 60 A
V_{RRM} = 300 V
t_{rr} = 30 ns

V _{RSM} V	V _{RRM} V	Type
300	300	DSEP 60-03A



A = Anode, C = Cathode, TAB = Cathode

Symbol	Conditions	Maximum Ratings	
I _{FRMS}		70	A
I _{FAVM}	T _C = 110°C; rectangular, d = 0.5	60	A
I _{FSM}	T _{VJ} = 45°C; t _p = 10 ms (50 Hz), sine	700	A
E _{AS}	T _{VJ} = 25°C; non-repetitive I _{AS} = 3.5 A; L = 180 µH	1.6	mJ
I _{AR}	V _A = 1.5·V _R typ.; f = 10 kHz; repetitive	0.4	A
T _{VJ}		-55...+175	°C
T _{VJM}		175	°C
T _{stg}		-55...+150	°C
P _{tot}	T _C = 25°C	230	W
M _d	mounting torque	0.8...1.2	Nm
Weight	typical	6	g

Symbol	Conditions	Characteristic Values	
		typ.	max.
I _R ①	T _{VJ} = 25°C V _R = V _{RRM} T _{VJ} = 150°C V _R = V _{RRM}	650 2.5	µA mA
V _F ②	I _F = 60 A; T _{VJ} = 150°C T _{VJ} = 25°C	1.25 1.71	V V
R _{thJC} R _{thCH}		0.25	K/W K/W
t _{rr}	I _F = 1 A; -di/dt = 300 A/µs; V _R = 30 V; T _{VJ} = 25°C	30	ns
I _{RM}	V _R = 100 V; I _F = 130 A; -di _F /dt = 100 A/µs T _{VJ} = 100°C	4.8	A

Pulse test: ① Pulse Width = 5 ms, Duty Cycle < 2.0 %
 ② Pulse Width = 300 µs, Duty Cycle < 2.0 %

Data according to IEC 60747 and per diode unless otherwise specified

IXYS reserves the right to change limits, test conditions and dimensions.

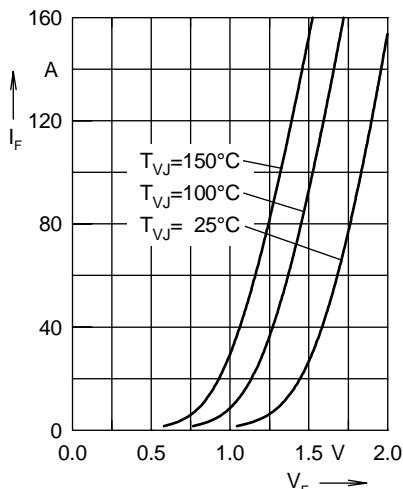


Fig. 1 Forward current I_F versus V_F

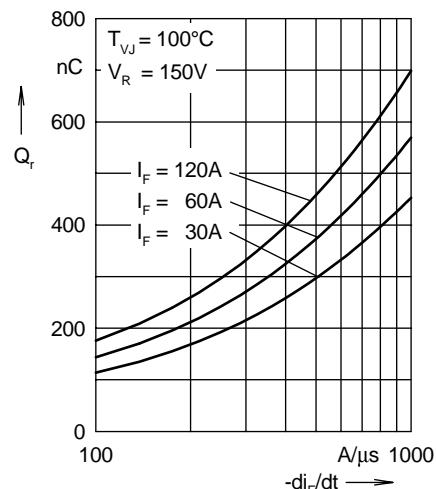


Fig. 2 Reverse recovery charge Q_r versus $-di_F/dt$

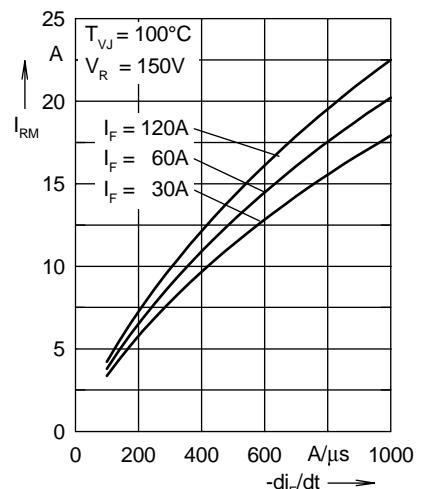


Fig. 3 Peak reverse current I_{RM} versus $-di_F/dt$

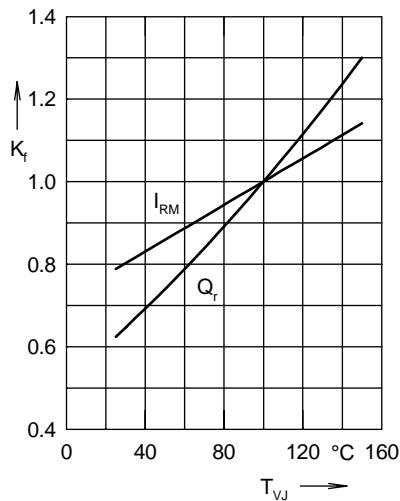


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

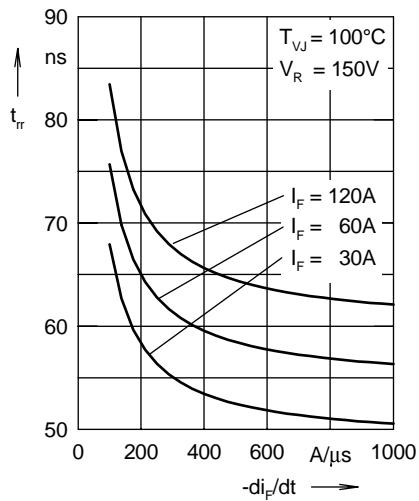


Fig. 5 Recovery time t_{rr} versus $-di_F/dt$

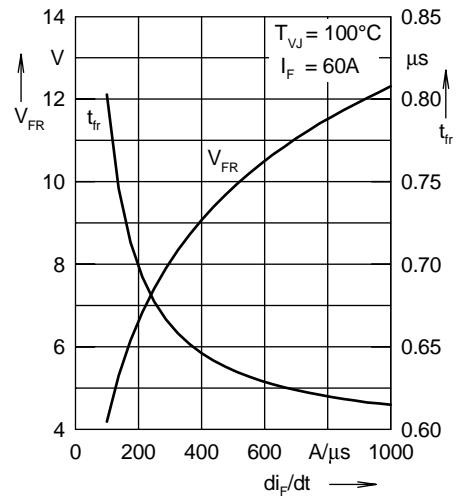


Fig. 6 Peak forward voltage V_{FR} and t_{tr} versus di_F/dt

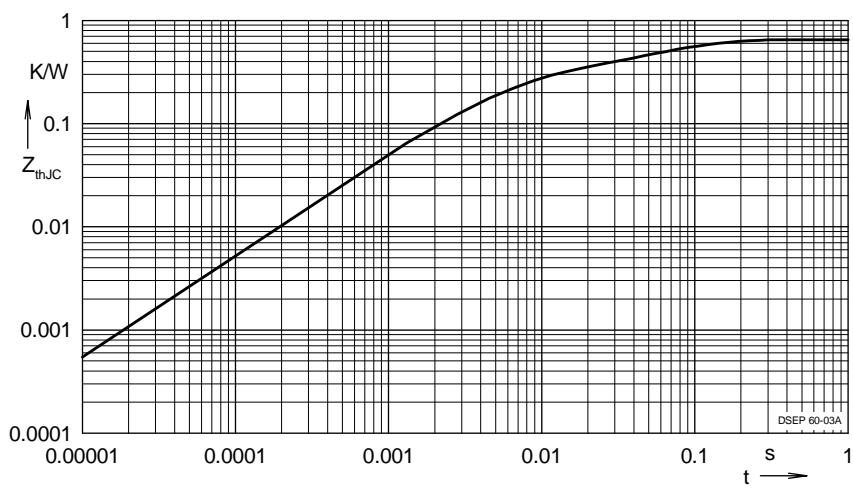


Fig. 7 Transient thermal resistance junction to case

NOTE: Fig. 2 to Fig. 6 shows typical values

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